

FAST CMOS 20-BIT BUFFER

IDT74FCT162827AT/CT

FEATURES:

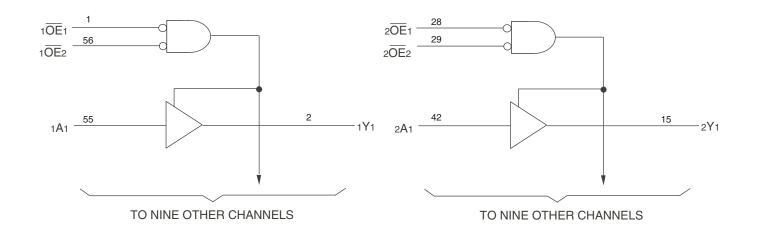
- 0.5 MICRON CMOS Technology
- · High-speed, low-power CMOS replacement for ABT functions
- Typical tsk(o) (Output Skew) < 250ps
- Low input and output leakage ≤1µA (max.)
- ESD > 2000V per MIL-STD-883, Method 3015; > 200V using machine model (C = 200pF, R = 0)
- VCC = 5V ±10%
- Balanced Output Drivers (±24mA)
- · Reduced system switching noise
- Typical VOLP (Output Ground Bounce) < 0.6V at Vcc = 5V, TA = 25°C
- · Available in SSOP and TSSOP packages

DESCRIPTION:

The FCT162827T 20-bit buffers are built using advanced dual metal CMOS technology. These 20-bit bus drivers provide high-performance bus interface buffering for wide data/address paths or buses carrying parity. Two pair of NAND-ed output enable controls offer maximum control flexibility and are organized to operate the device as two 10-bit buffers or one 20-bit buffer. Flow-through organization of signal pins simplifies layout. All inputs are designed with hysteresis for improved noise margin.

The FCT162827T has balanced output drive with current limiting resistors. This offers low ground bounce, minimal undershoot, and controlled output fall times–reducing the need for external series terminating resistors. The FCT162827T is a plug-in replacement for the FCT16827T and ABT16827 for on-board interface applications.

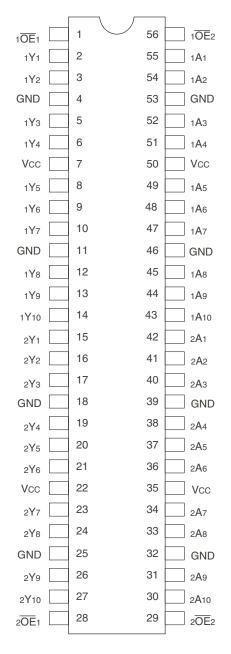
FUNCTIONAL BLOCK DIAGRAM



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INDUSTRIAL TEMPERATURE RANGE

PIN CONFIGURATION



SSOP/ TSSOP TOP VIEW

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Terminal Voltage with Respect to GND	–0.5 to 7	V
VTERM ⁽³⁾	Terminal Voltage with Respect to GND -0.5 to Vo		V
Tstg	Storage Temperature	-65 to +150	°C
Ιουτ	DC Output Current	-60 to +120	mA

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. All device terminals except FCT162XXX Output and I/O terminals.

3. Outputs and I/O terminals for FCT162XXX.

CAPACITANCE (TA = +25°C, f = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Тур.	Max.	Unit
CIN	Input Capacitance	VIN = 0V	3.5	6	pF
Соит	Output Capacitance	Vout = 0V	3.5	8	pF

NOTE:

1. This parameter is measured at characterization but not tested.

PIN DESCRIPTION

Pin Names Description	
xŌĒx	Output Enable Inputs (Active LOW)
хАх	DataInputs
хҮх	3-State Outputs

FUNCTION TABLE(1)

	Outputs		
xOE1	xOE2	хАх	хҮх
L	L	L	L
L	L	Н	Н
Н	Х	Х	Z
Х	Н	Х	Z

NOTE:

1. H = HIGH voltage level

L = LOW voltage level

X = Don't care

Z = High-impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C, Vcc = $5.0V \pm 10\%$

Symbol	Parameter	Test Conditions	(1)	Min.	Тур. ⁽²⁾	Max.	Unit
Vih	Input HIGH Level	Guaranteed Logic HIGH Level		2	—	_	V
VIL	Input LOW Level	Guaranteed Logic LOW Level		_	—	0.8	V
Ін	Input HIGH Current (Input pins) ⁽⁴⁾	Vcc = Max.	VI = VCC	_	_	±1	μA
	Input HIGH Current (I/O pins) ⁽⁴⁾]		_	—	±1	
١L	Input LOW Current (Input pins) ⁽⁴⁾]	VI = GND	_	—	±1	
	Input LOW Current (I/O pins) ⁽⁴⁾			_	—	±1	
Іоzн	High Impedance Output Current	Vcc = Max.	Vo = 2.7V	_	—	±1	μA
Iozl	(3-State Output pins) ⁽⁴⁾		Vo = 0.5V	_	—	±1	
Vik	Clamp Diode Voltage	Vcc = Min., IIN = -18mA		_	-0.7	-1.2	V
los	Short Circuit Current	Vcc = Max., Vo = GND ⁽³⁾		-80	-140	-250	mA
Vн	Input Hysteresis	_		_	100	-	mV
ICCL	Quiescent Power Supply Current	Vcc = Max		_	5	500	μA
Іссн		VIN = GND or VCC					
Iccz							

OUTPUT DRIVE CHARACTERISTICS

Symbol	Parameter	Test Condit	Test Conditions ⁽¹⁾		Typ. ⁽²⁾	Max.	Unit
IODL	Output LOW Current	$VCC = 5V$, $VIN = VIH$ or VIL , $VO = 1.5V^{(3)}$		60	115	200	mA
IODH	Output HIGH Current	VCC = 5V, VIN = VIH or VIL, VO = $1.5V^{(3)}$		-60	-115	-200	mA
Vон	Output HIGH Voltage	Vcc = Min.	Iон = –24mA	2.4	3.3	_	V
		VIN = VIH or VIL					
Vol	Output LOW Voltage	Vcc = Min.	Iol = 24mA	_	0.3	0.55	V
		VIN = VIH or VIL					

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.

4. This test limit for this parameter is $\pm 5\mu$ A at TA = -55°C.

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Min.	Typ. ⁽²⁾	Max.	Unit
Δlcc	Quiescent Power Supply Current TTL Inputs HIGH	$V_{CC} = Max.$ VIN = 3.4V ⁽³⁾		-	0.5	1.5	mA
ICCD	Dynamic Power Supply Current ⁽⁴⁾	Vcc = Max. Outputs Open $x\overline{OE}1 = x\overline{OE}2 = GND$ One Input Toggling 50% Duty Cycle	Vin = Vcc Vin = GND	_	60	100	μΑ/ MHz
Ic	Total Power Supply Current ⁽⁶⁾	Vcc = Max. Outputs Open fi = 10MHz 50% Duty Cycle $x\overline{OE_1} = x\overline{OE_2} = GND$	VIN = VCC VIN = GND VIN = 3.4V VIN = GND	-	0.6	1.5 2.3	mA
		One Bit Toggling Vcc = Max. Outputs Open	VIN = VCC VIN = GND	-	3	5.5 ⁽⁵⁾	
		fi = 2.5MHz 50% Duty_Cycle xOE1 = xOE2 = GND Twenty Bits Toggling	VIN = 3.4V VIN = GND	_	8	20.5 ⁽⁵⁾	

NOTES:

1. For conditions shown as Min. or Max., use appropriate value specified under Electrical Characteristics for the applicable device type.

2. Typical values are at Vcc = 5.0V, +25°C ambient.

3. Per TTL driven input ($V_{IN} = 3.4V$). All other inputs at Vcc or GND.

4. This parameter is not directly testable, but is derived for use in Total Power Supply Calculations.

5. Values for these conditions are examples of the Icc formula. These limits are guaranteed but not tested.

6. IC = IQUIESCENT + INPUTS + IDYNAMIC

 $IC = ICC + \Delta ICC DHNT + ICCD (fCPNCP/2 + fiNi)$

Icc = Quiescent Current (IccL, IccH and Iccz)

 Δ Icc = Power Supply Current for a TTL High Input (VIN = 3.4V)

DH = Duty Cycle for TTL Inputs High

NT = Number of TTL Inputs at DH

ICCD = Dynamic Current Caused by an Input Transition Pair (HLH or LHL)

fcp = Clock Frequency for Register Devices (Zero for Non-Register Devices)

NCP = Number of Clock Inputs at fCP

fi = Input Frequency

Ni = Number of Inputs at fi

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

			FCT162	2827AT	FCT16	2827CT	
Symbol	Parameter	Condition ⁽¹⁾	Min. ⁽²⁾	Max.	Min. ⁽²⁾	Max.	Unit
t PLH	Propagation Delay	CL = 50pF	1.5	8	1.5	3.7	ns
t PHL	xAx to xYx	RL = 500Ω					
		CL = 300pF ⁽⁴⁾	1.5	15	1.5	7]
		RL = 500Ω					
tpzh	Output Enable Time	CL = 50pF	1.5	12	.5	4.8	ns
tPZL	x OE x to xYx	RL = 500Ω					
		CL = 300pF ⁽⁴⁾	1.5	23	1.5	9	1
		RL = 500Ω					
tphz	Output Disable Time	$CL = 5pF^{(4)}$	1.5	9	1.5	4	ns
tPLZ	xOEx to xYx	RL = 500Ω					
		CL = 50pF	1.5	10	1.5	4	1
		RL = 500Ω					
tsk(o)	Output Skew ⁽³⁾		—	0.5	—	0.5	ns

NOTES:

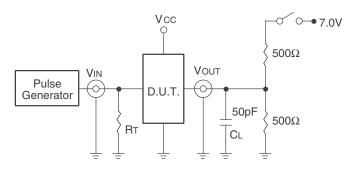
1. See test circuit and waveforms.

2. Minimum limits are guaranteed but not tested on Propagation Delays.

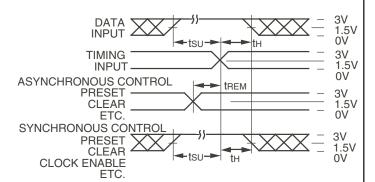
3. Skew between any two outputs, of the same package, switching in the same direction. This parameter is guaranteed by design.

4. This limit is guaranteed but not tested.

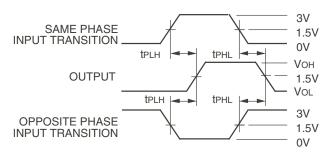
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-up, Hold, and Release Times



Propagation Delay

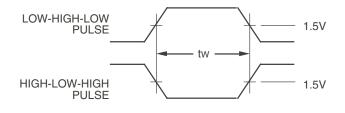
SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

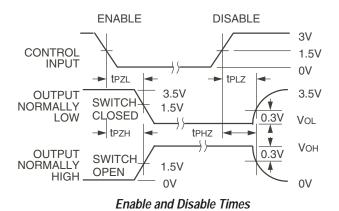
DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



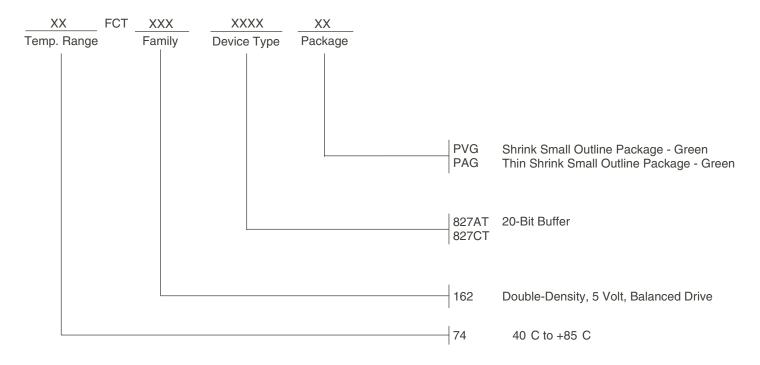
Pulse Width



NOTES:

- 1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- 2. Pulse Generator for All Pulses: Rate \leq 1.0MHz; tr \leq 2.5ns; tr \leq 2.5ns.

ORDERING INFORMATION



Datasheet Document History

09/06/09 Pg. 7 Updated the ordering information by removing the "IDT" notation and non RoHS part.

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